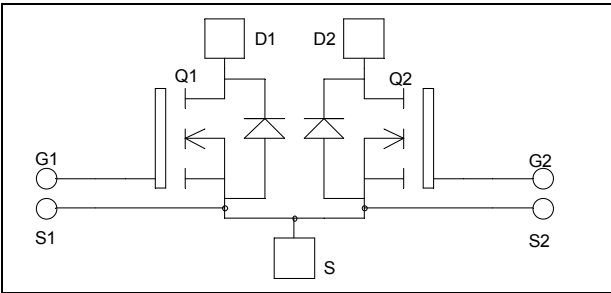


Dual common source MOSFET Power Module

$V_{DSS} = 1200V$
 $R_{DSon} = 150m\Omega$ typ @ $T_j = 25^\circ C$
 $I_D = 60A$ @ $T_c = 25^\circ C$



Application

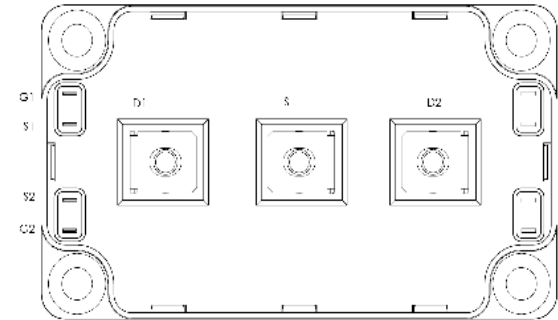
- AC Switches
- Switched Mode Power Supplies
- Uninterruptible Power Supplies

Features

- Power MOS 7[®] MOSFETs
 - Low R_{DSon}
 - Low input and Miller capacitance
 - Low gate charge
 - Avalanche energy rated
 - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
 - Symmetrical design
 - M5 power connectors
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Low profile
- RoHS Compliant



Absolute maximum ratings

Symbol	Parameter	Max ratings	Unit
V_{DSS}	Drain - Source Breakdown Voltage	1200	V
I_D	Continuous Drain Current	$T_c = 25^\circ C$	60
		$T_c = 80^\circ C$	45
I_{DM}	Pulsed Drain current	240	A
V_{GS}	Gate - Source Voltage	± 30	V
R_{DSon}	Drain - Source ON Resistance	175	$m\Omega$
P_D	Maximum Power Dissipation	$T_c = 25^\circ C$	1250
I_{AR}	Avalanche current (repetitive and non repetitive)	22	A
E_{AR}	Repetitive Avalanche Energy	50	mJ
E_{AS}	Single Pulse Avalanche Energy	3000	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

All ratings @ $T_j = 25^\circ\text{C}$ unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit	
I _{DSS}	Zero Gate Voltage Drain Current	V _{GS} = 0V, V _{DS} = 1200V	T _j = 25°C			500	μA
		V _{GS} = 0V, V _{DS} = 1000V	T _j = 125°C			3000	
R _{DS(on)}	Drain – Source on Resistance	V _{GS} = 10V, I _D = 30A		150	175	mΩ	
V _{GS(th)}	Gate Threshold Voltage	V _{GS} = V _{DS} , I _D = 10mA	3		5	V	
I _{GSS}	Gate – Source Leakage Current	V _{GS} = ±30 V, V _{DS} = 0V			±250	nA	

Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
C _{iss}	Input Capacitance	V _{GS} = 0V V _{DS} = 25V f = 1MHz		20.6		nF
C _{oss}	Output Capacitance			3.08		
C _{rss}	Reverse Transfer Capacitance			0.52		
Q _g	Total gate Charge	V _{GS} = 10V V _{Bus} = 600V I _D = 60A		748		nC
Q _{gs}	Gate – Source Charge			96		
Q _{gd}	Gate – Drain Charge			480		
T _{d(on)}	Turn-on Delay Time	Inductive switching @ 125°C V _{GS} = 15V V _{Bus} = 800V I _D = 60A R _G = 1.2Ω		20		ns
T _r	Rise Time			15		
T _{d(off)}	Turn-off Delay Time			160		
T _f	Fall Time			45		
E _{on}	Turn-on Switching Energy	Inductive switching @ 25°C V _{GS} = 15V, V _{Bus} = 800V I _D = 60A, R _G = 1.2Ω		3.96		mJ
E _{off}	Turn-off Switching Energy			2.74		
E _{on}	Turn-on Switching Energy	Inductive switching @ 125°C V _{GS} = 15V, V _{Bus} = 800V I _D = 60A, R _G = 1.2Ω		6.26		mJ
E _{off}	Turn-off Switching Energy			3.43		

Source - Drain diode ratings and characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit	
I _S	Continuous Source current (Body diode)		T _c = 25°C			60	A
			T _c = 80°C			45	
V _{SD}	Diode Forward Voltage	V _{GS} = 0V, I _S = - 60A			1.3	V	
dv/dt	Peak Diode Recovery ❶				10	V/ns	
t _{rr}	Reverse Recovery Time	I _S = - 60A, V _R = 600V di _S /dt = 400A/μs		1291		ns	
Q _{rr}	Reverse Recovery Charge			116		μC	

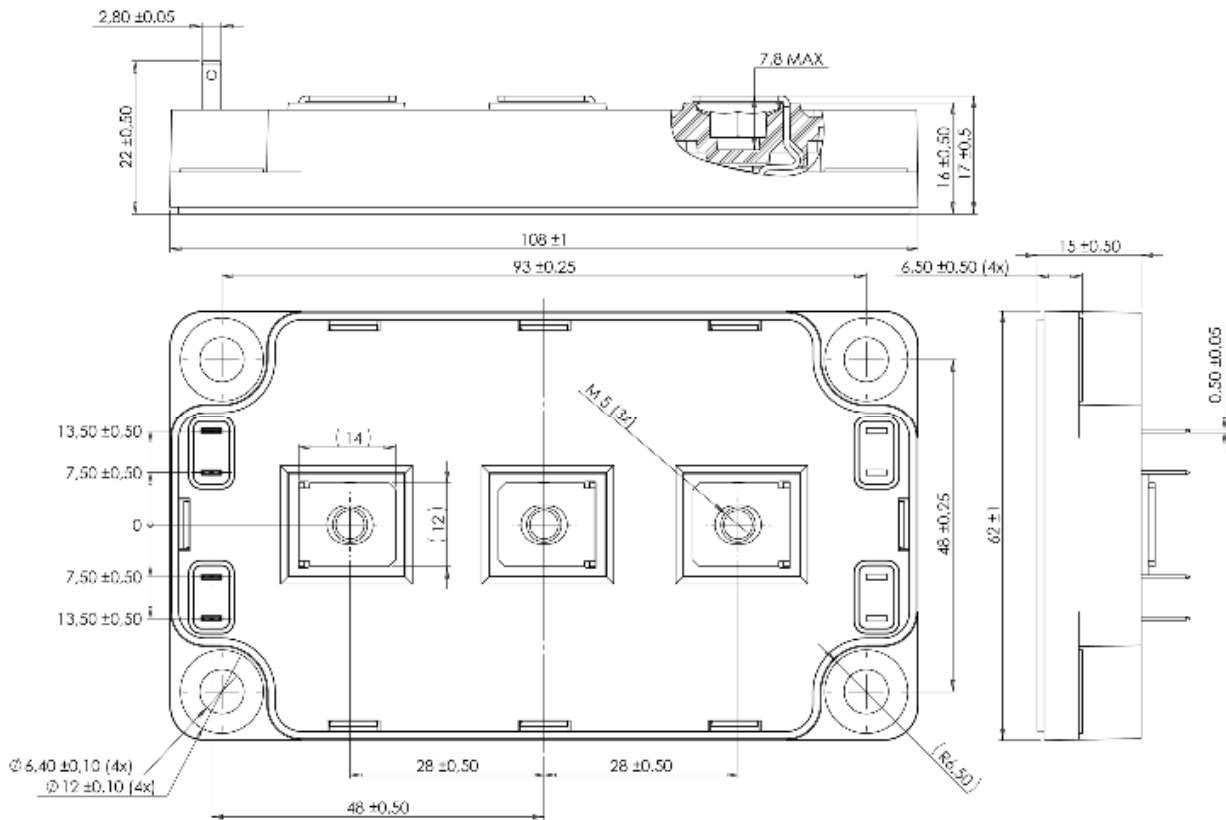
❶ dv/dt numbers reflect the limitations of the circuit rather than the device itself.

I_S ≤ - 60A di_S/dt ≤ 700A/μs V_R ≤ V_{DSS} T_j ≤ 150°C

Thermal and package characteristics

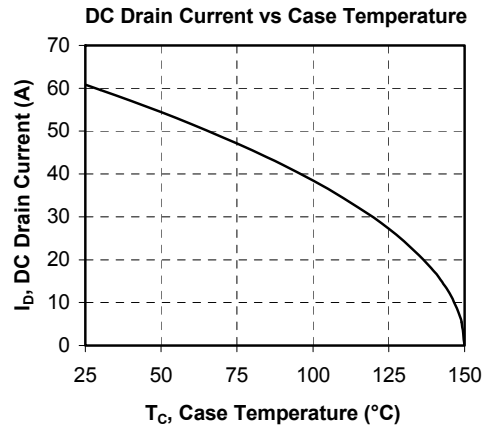
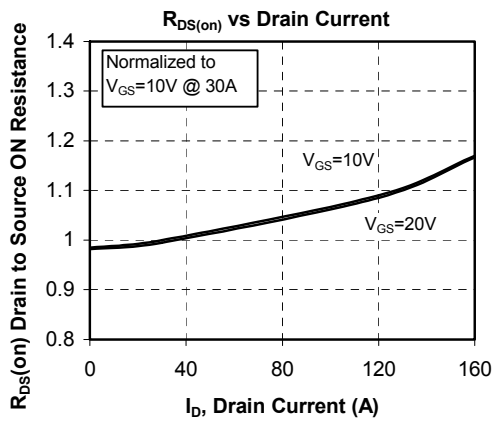
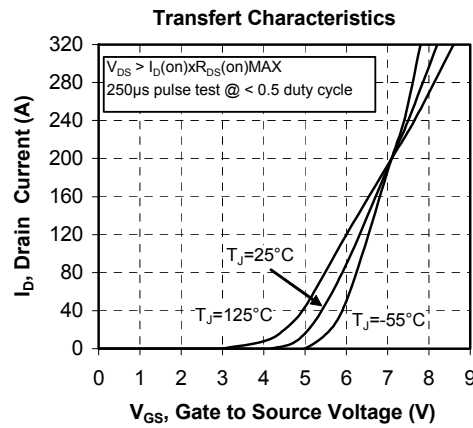
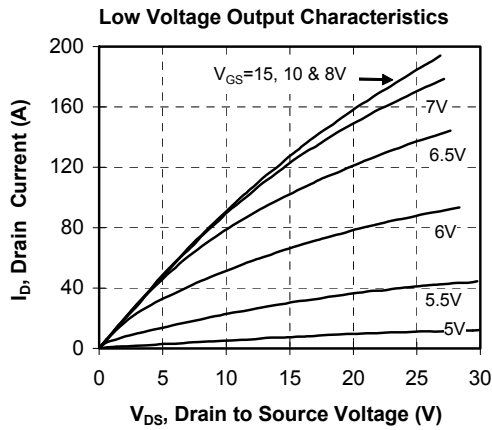
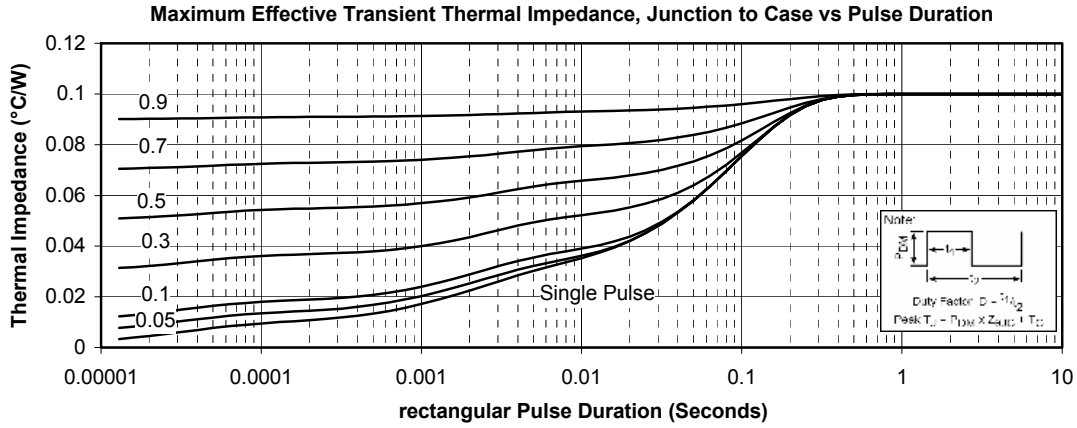
Symbol	Characteristic	Min	Typ	Max	Unit	
R _{thJC}	Junction to Case Thermal Resistance			0.1	°C/W	
V _{ISOL}	RMS Isolation Voltage, any terminal to case t=1 min, 50/60Hz	4000			V	
T _J	Operating junction temperature range	-40		150	°C	
T _{STG}	Storage Temperature Range	-40		125		
T _C	Operating Case Temperature	-40		100		
Torque	Mounting torque	To heatsink	M6	3	5	N.m
		For terminals	M5	2	3.5	
Wt	Package Weight			300	g	

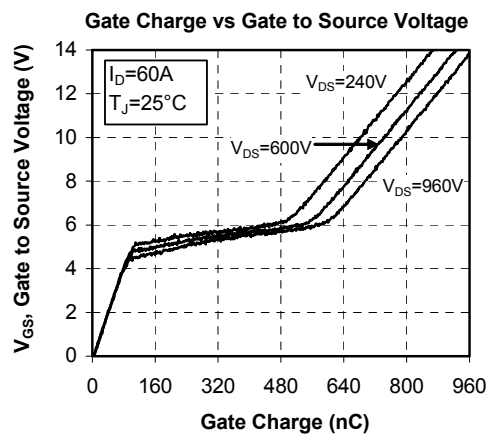
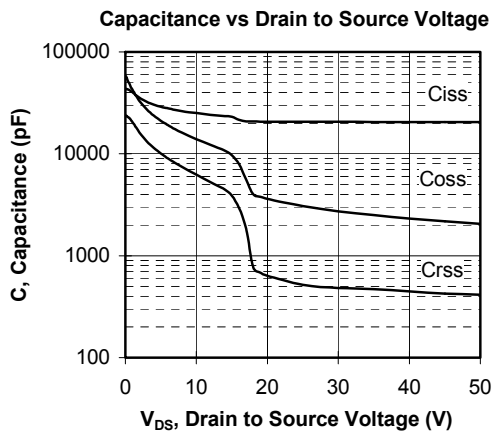
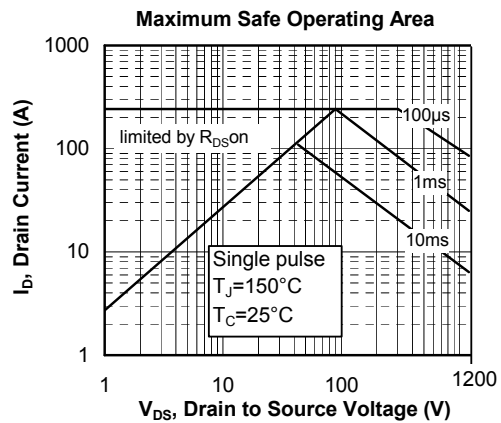
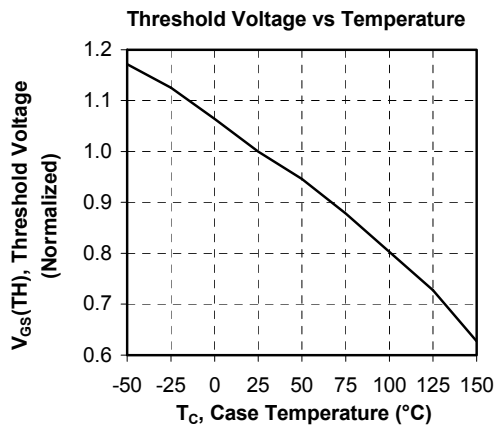
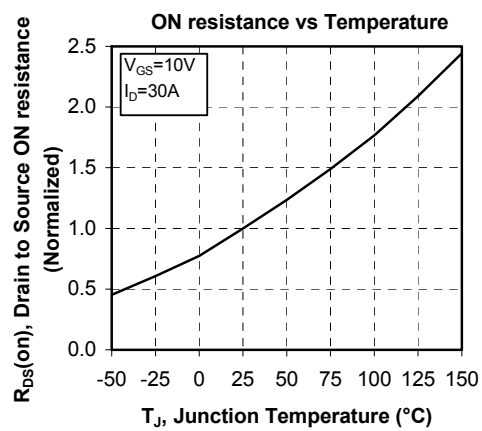
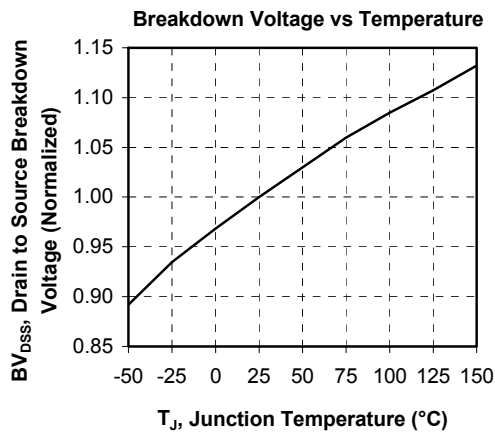
SP6 Package outline (dimensions in mm)

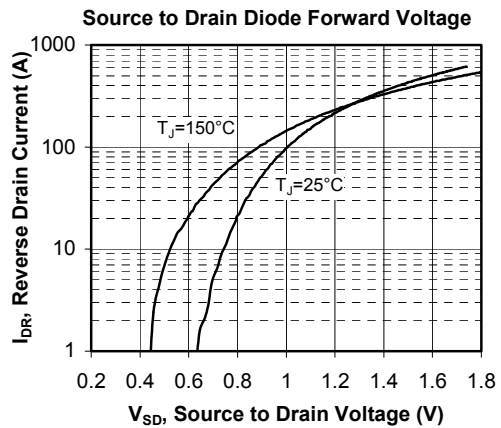
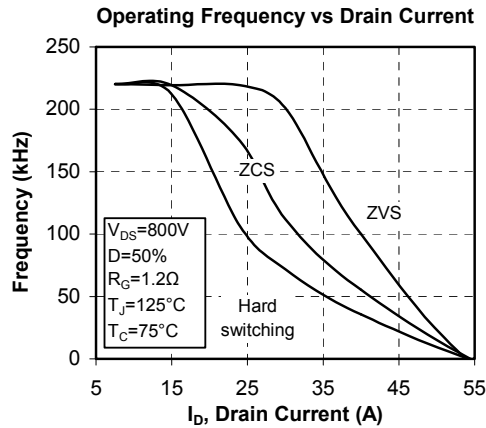
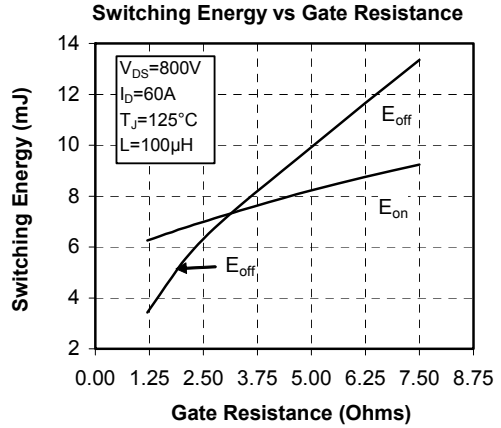
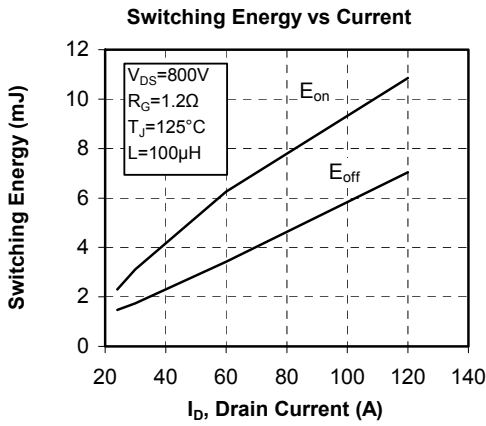
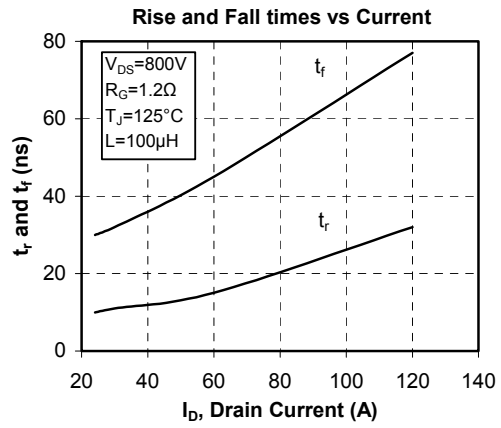
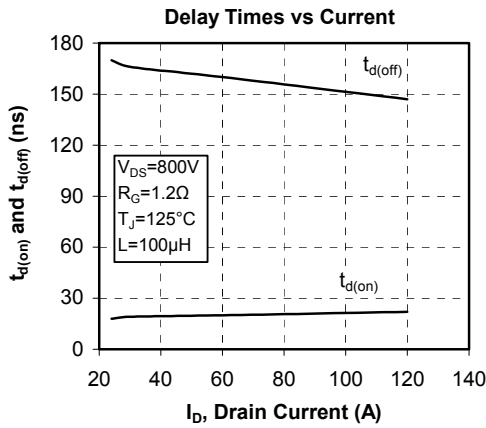


See application note APT0601 - Mounting Instructions for SP6 Power Modules on www.microsemi.com

Typical Performance Curve







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